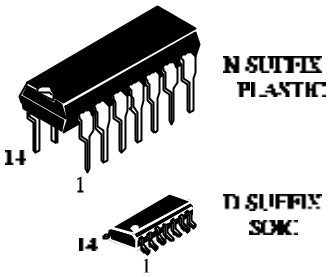
SL74LV14

Hex Schmitt-Trigger Inverter

The 74LV14 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT14.

The 74LV14 provides six inverting buffers with Schmitt-trigger action.

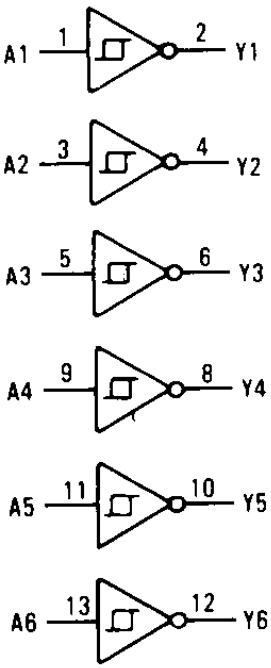
- Wide Operating Voltage: 1.0 to 5.5 V
- Optimized for Low Voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between V_{CC} =2.7 V and V_{CC} =3.6 V
- Low input current



ORDERING INFORMATION

SL74LV14N Plastic
SL74LV14D SOIC
SL74LV14 Chip
T_A = -40° ÷ 125° C for all packages

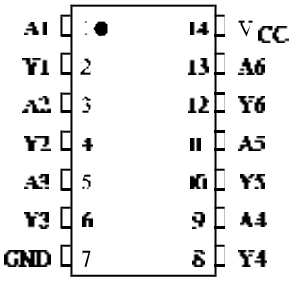
LOGIC DIAGRAM



$Y = \overline{A}$

PIN 14 =V_{CC}
PIN 7 = GND

PIN ASSIGNMENT



FUNCTION TABLE

Input	Output
A	$Y = \overline{A}$
L	H
H	L

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC supply voltage (Referenced to GND)	-0.5 ~ +7.0	V
I_{IK}*[1]	DC input diode current	±20	mA
I_{OK}*[2]	DC output diode current	±50	mA
Io*[3]	DC output source or sink current -bus driver outputs	±25	mA
I_{GND}	DC GND current for types with - bus driver outputs	±50	mA
I_{CC}	DC V_{CC} current for types with - bus driver outputs	±50	mA
P_D	Power dissipation per paskade, plastic DIP+ SOIC package+	750 500	mW
Tstg	Storage temperature	-65 ~ +150	°C
T_L	Lead temperature, 1.5 mm from Case for 10 seconds (Plastic DIP), 0.3 mm (SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.
Functional operation should be restricted to the Recommended Operating Conditions.
+Derating - Plastic DIP: - 12 mW/°C from 70° to 125°C
SOIC Package: : - 8 mW/°C from 70° to 125°C
*[1]: $V_I < -0.5V$ or $V_I > V_{CC}+0.5V$
*[2]: $Vo < -0.5V$ or $Vo > V_{CC}+0.5V$
*[3]: $-0.5V < Vo < V_{CC}+0.5V$

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)		1.0	5.5	V
V_{IN}, V_{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)		0	V_{CC}	V
T_A	Operating Temperature, All Package Types		-40	+125	°C
t_r, t_f	Input Rise and Fall Time	1.0 V≤V_{CC} <2.0 V	0	500	ns
		2.0 V≤V_{CC} <2.7 V	0	200	
		2.7 V≤V_{CC} <3.6 V	0	100	
		3.6 V≤V_{CC} ≤5.5 V	0	50	

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND≤(V_{IN} or V_{OUT})≤V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit						Unit
				25°C		-40°C ÷ 85°C		-40°C ÷ 125°C		
				min	max	min	max	min	max	
V_{IT}+	Positive-Going Input Threshold Voltage	$V_O \geq V_{OH}$	1.2	0.45	0.95	0.4	1.0	0.4	1.0	V
			2.0	0.85	1.35	0.8	1.4	0.8	1.4	
			2.7	1.05	1.95	1.0	2.0	1.0	2.0	
			3.0	1.25	2.15	1.2	2.2	1.2	2.2	
			3.6	1.55	2.35	1.5	2.4	1.5	2.4	
			4.5	1.75	3.10	1.7	3.15	1.7	3.15	
			5.5	2.15	3.80	2.1	3.85	2.1	3.85	
V_{IT}-	Negative-Going Input Threshold Voltage	$V_O \leq V_{OL}$	1.2	0.2	0.65	0.15	0.7	0.15	0.7	V
			2.0	0.35	0.85	0.3	0.9	0.3	0.9	
			2.7	0.45	1.35	0.4	1.4	0.4	1.4	
			3.0	0.65	1.45	0.6	1.5	0.6	1.5	
			3.6	0.85	1.75	0.8	1.8	0.8	1.8	
			4.5	0.95	1.95	0.9	2.0	0.9	2.0	
			5.5	1.15	1.15	1.1	2.26	1.1	2.26	
V_H	Hysteresis Voltage	$V_O \geq V_{OH}$ $V_O \leq V_{OL}$	1.2	0.2	0.65	0.15	0.7	0.15	0.7	V
			2.0	0.25	0.75	0.3	0.9	0.3	0.9	
			2.7	0.35	1.05	0.4	1.4	0.4	1.4	
			3.0	0.45	1.15	0.6	1.5	0.6	1.5	
			3.6	0.45	1.15	0.8	1.8	0.8	1.8	
			4.5	0.45	1.35	0.9	2.0	0.9	2.0	
			5.5	0.65	1.45	1.1	2.6	1.1	2.6	
V_{OH}	High-Level Output Voltage	$V_I = V_{IH}$ –or V_{IL} I_O = -100 µA	1.2	1.05	-	1.0	-	1.0	-	V
			2.0	1.85	-	1.8	-	1.8	-	
			2.7	2.55	-	2.5	-	2.5	-	
			3.0	2.85	-	2.8	-	2.8	-	
			3.6	3.45	-	3.4	-	3.4	-	
			4.5	4.35	-	4.3	-	4.3	-	
			5.5	5.35	-	5.3	-	5.3	-	
V_{OH}	High-Level Output Voltage	$V_I = V_{IH}$ –or V_{IL} I_O = -6.0 mA	3.0	2.48	-	2.40	-	2.20	-	V
		$V_I = V_{IH}$ –or V_{IL} I_O = -12.0 mA	4.5	3.70	-	3.60	-	3.50	-	
V_{OL}	Low-Level Output Voltage	$V_I = V_{IH}$ –or V_{IL} I_O = 100 µA	1.2	-	0.15	-	0.2	-	0.2	V
			2.0	-	0.15	-	0.2	-	0.2	
			2.7	-	0.15	-	0.2	-	0.2	
			3.0	-	0.15	-	0.2	-	0.2	
			3.6	-	0.15	-	0.2	-	0.2	
			4.5	-	0.15	-	0.2	-	0.2	
			5.5	-	0.15	-	0.2	-	0.2	

DC ELECTRICAL CHARACTERISTICS (continuation)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit						Unit
				25°C		-40°C ÷ 85°C		-40°C ÷ 125°C		
				min	max	min	max	min	max	
V_{OL}	Low-Level Output Voltage	$V_I = V_{IH}$ –or I_O = 6.0 mA	3.0	-	0.33	-	0.40	-	0.50	V
		$V_I = V_{IH}$ –or V_{IL} I_O = 12.0 mA	4.5	-	0.40	-	0.55	-	0.65	
I_{IL}	Low-Level Input Leakage Current	V_I=0 V	5.5	-	-0.1	-	-1.0	-	-1.0	µA
I_{IH}	High-Level Input Leakage Current	V_I= $V_{ÑÑ}$	5.5	-	0.1	-	1.0	-	1.0	
I_{CC}	Quiescent Supply Current (per Package)	V_I=0 Âor $V_{ÑÑ}$ I_O = 0 µA	5.5	-	4.0	-	20	-	40	µA
I_{CC1}	Additional Quiescent Supply Current on input	V_I = $V_{ÑÑ}$- 0.6V I_O = 0 µA	2.7 3.6	-	0.2	-	0.5	-	0.85	mA

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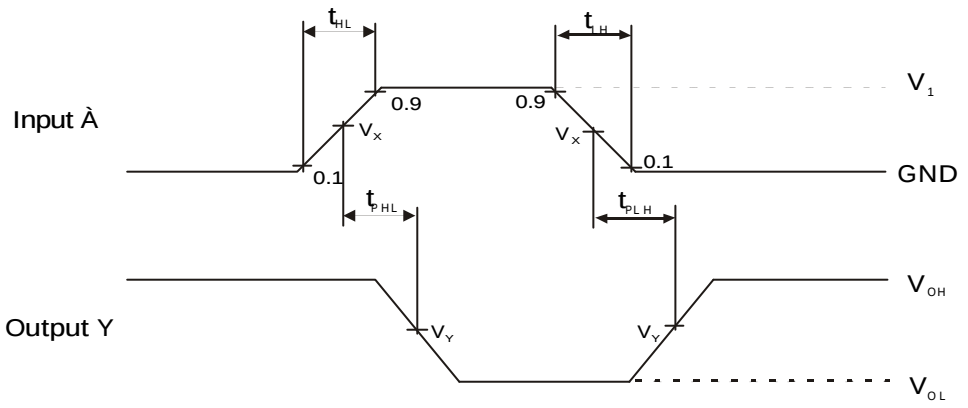
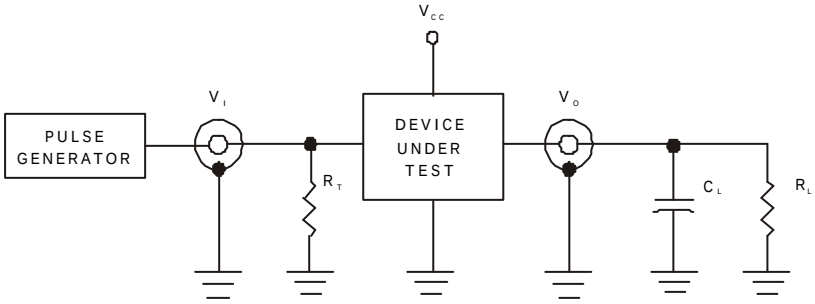
AC ELECTRICAL CHARACTERISTICS (C_L=50 pF, t_{LH} =t_{HL} = 2.5 ns, R_L=1 kÙ)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit						Unit
				25°C		-40°C ÷ 85°C		-40°C ÷ 125°C		
				min	max	min	max	min	max	
t_{PLH}, t_{PHL}	Propagation Delay, Input A to Output Y (Figure 1)	V_I=0 V or V_1 t_{LH} = t_{HL} =2.5 ns $\tilde{N}_L$ = 50 pF R_L = 1 kÙ	1.2 2.0 2.7 3.0 4.5	- - - - -	150 28 22 17 14	- - - - -	170 37 28 22 18	- - - - -	200 48 35 28 23	ns
C_I	Input Capacitance		5.5	-	7.0	-	7.0	-	7.0	pF
C_{PD}		V_I=0 V or $V_{\tilde{N}\tilde{N}}$	5.5	-	30	-	30	-	30	pF



V_X=0.5 V_{CC}

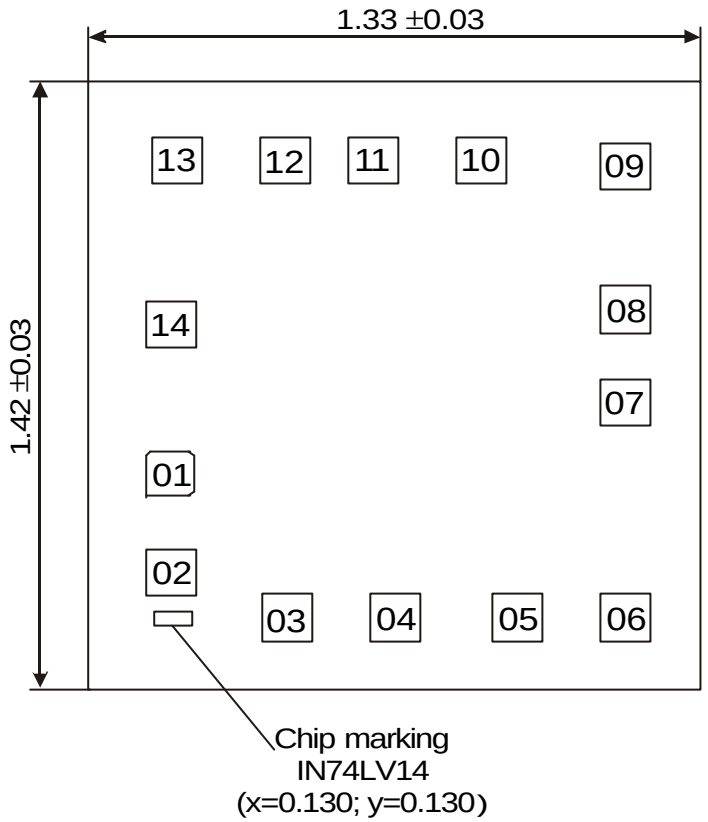
Figure 1. Switching Waveforms



Termination resistance R_T – should be equal to Z_{OUT} of pulse generators

Figure 2. Test Circuit

CHIP PAD DIAGRAM SL74LV14



Pad size 0.108 x 0.108 mm (Pad size is given as per metallization layer)
Thickness of chip 0.46 ± 0,02 mm

PAD LOCATION

Pad No	Symbol	X	Y
01	A1	0.130	0.463
02	Y1	0.130	0.230
03	A2	0.381	0.126
04	Y2	0.616	0.126
05	A3	0.881	0.126
06	Y3	1.116	0.126
07	GND	1.115	0.631
08	Y4	1.115	0.846
09	A4	1.115	1.181
10	Y5	0.804	1.194
11	A5	0.569	1.194
12	Y6	0.378	1.194
13	A6	0.143	1.194
14	V_{CC}	0.130	0.813